

Small-Signal Chip Diode

Features

- This diode is also available in other case styles including the 1206 case with the type designation CD4148WP, the 0603 case with the type designation CD4148WTP
- Silicon Epitaxial Planar Diode
- Fast switching diode.

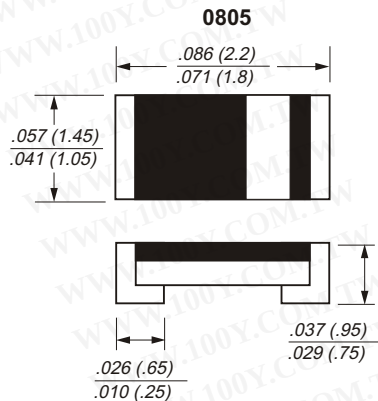
Mechanical Data

Case:0805

Weight : approx. 6 mg

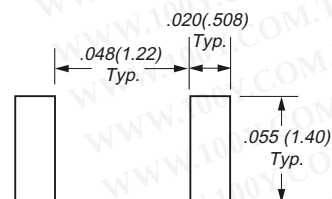
Marking : Cathode band

勝特力材料 886-3-5753170
勝特力电子(上海) 86-21-54151736
勝特力电子(深圳) 86-755-83298787
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Dimensions in inches and (millimeters)

Mounting Pad Layout



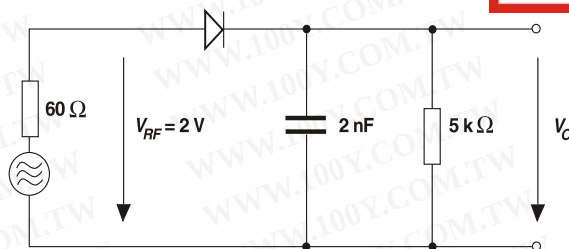
Absolute Maximum Ratings & Thermal Characteristics $T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Symbol	Value	Unit
Reverse voltage	V_R	75	V
Peak reverse voltage	V_{RM}	100	V
Forward continuous current	I_{FM}	300	mA
Average rectified current sin half wave rectification with resistive load $f \geq 50\text{ Hz}$	$I_{F(AV)}$	150 ¹⁾	mA
Surge forward current $t < 1\text{ s}$ and $T_j = 25\text{ }^{\circ}\text{C}$	I_{FSM}	500	mA
Power dissipation	P_{tot}	400 ¹⁾	mW
Typical Thermal Resistance Junction to Ambient Air	$R_{\theta JA}$	375 ¹⁾	K/W
Junction temperature	T_j	175	$^{\circ}\text{C}$
Storage temperature	T_S	- 65 to + 175	$^{\circ}\text{C}$

1) Valid provided that electrodes are kept at ambient temperature.

**Electrical Characteristics** $T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified

Parameter		Symbol	Min	Max	Unit
Forward voltage	$I_F = 10\text{ mA}$	V_F		1.0	V
Leakage current	$V_R = 20\text{ V}$	I_R		25	nA
	$V_R = 75\text{ V}$			5.0	μA
	$V_R = 20\text{ V}, T_J = 150^{\circ}\text{C}$			50	μA
Capacitance	$V_F = V_R = 0\text{ V}$	C_{tot}		4	pF
Voltage rise when switching ON	tested with 50 mA pulses, $t_p = 0.1\text{ }\mu\text{s}$, rise time $< 30\text{ ns}$, $f_p = (5\text{ to }100)\text{ kHz}$	V_{fr}		2.5	V
Reverse recovery time	$I_F = 10\text{ mA}$ to $I_R = 1\text{ mA}$, $V_R = 6\text{ V}, R_L = 100\text{ }\Omega$	t_{rr}		4	ns
Rectification efficiency	$f = 100\text{ MHz}, V_{RF} = 2\text{ V}$	η_r	45		%

Rectification Efficiency Measurement Circuit

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Typical Characteristics $(T_{amb} = 25^{\circ}\text{C})$ unless otherwise specified

Figure 1. Forward Characteristics

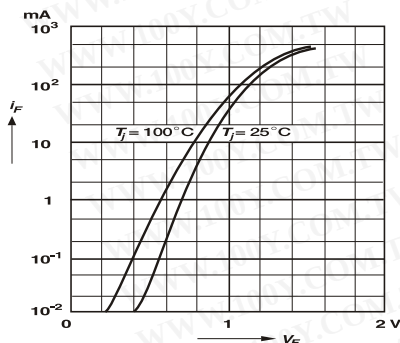
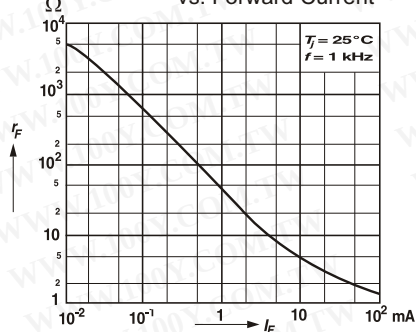
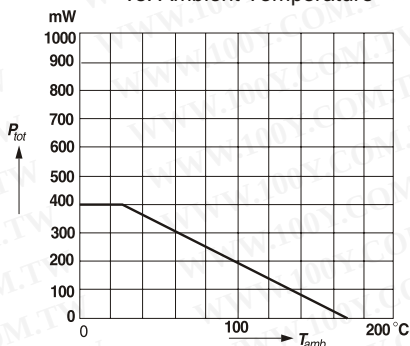
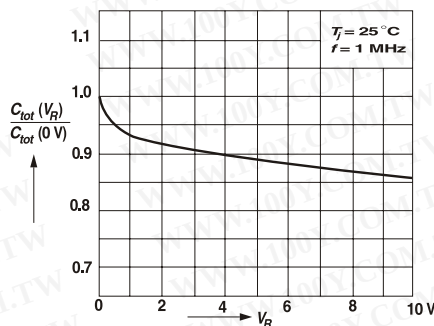
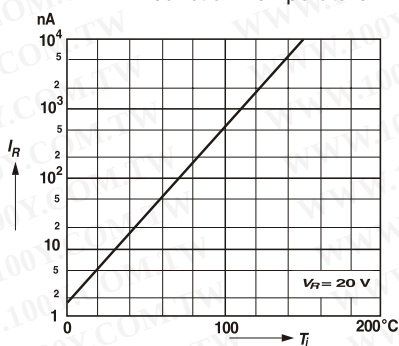
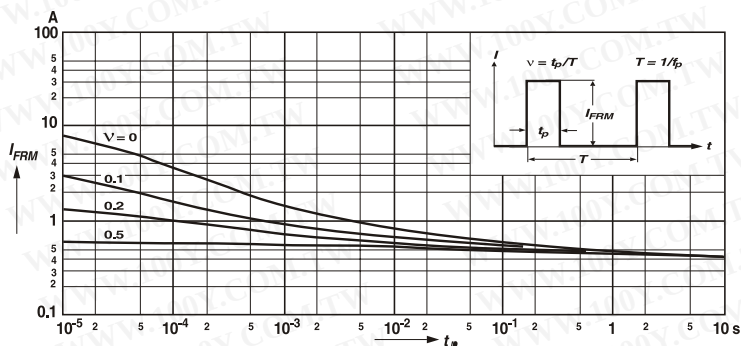


Figure 2. Dynamic Forward Resistance vs. Forward Current



**Figure 3. Admissible Power Dissipation vs. Ambient Temperature****Figure 4. Relative Capacitance vs. Reverse Voltage****Figure 5. Leakage Current vs. Junction Temperature**

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Figure 6. Admissible Repetitive Peak Forward Current vs. Pulse Duration

**Device outlook****Shanghai plant (front side)****Kunshan plant (front side)****Shanghai plant (back side)****Kunshan plant (back side)**

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Suggested thermal profiles for soldering processes

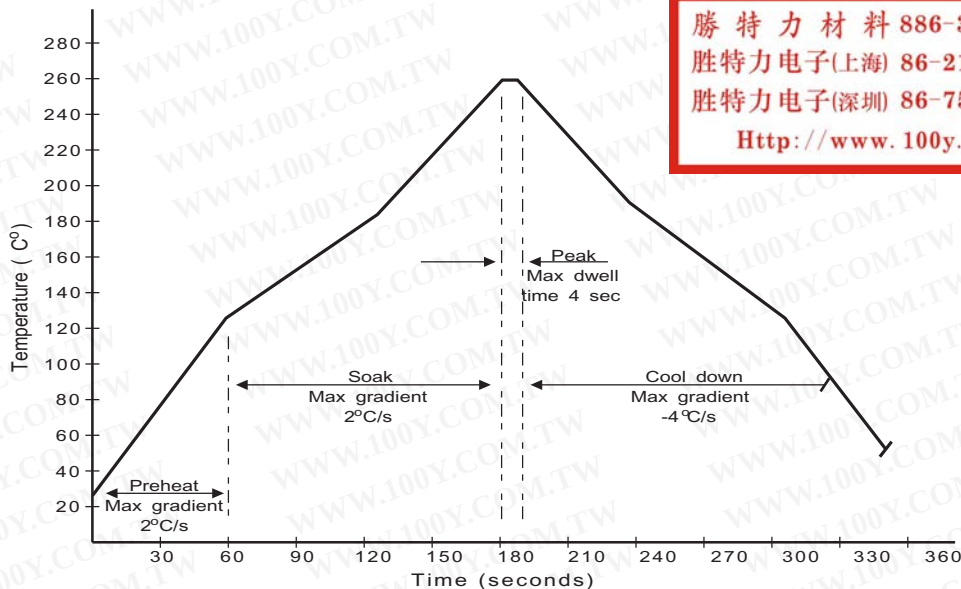


Fig.1 Typical Wave Soldering Thermal Profile

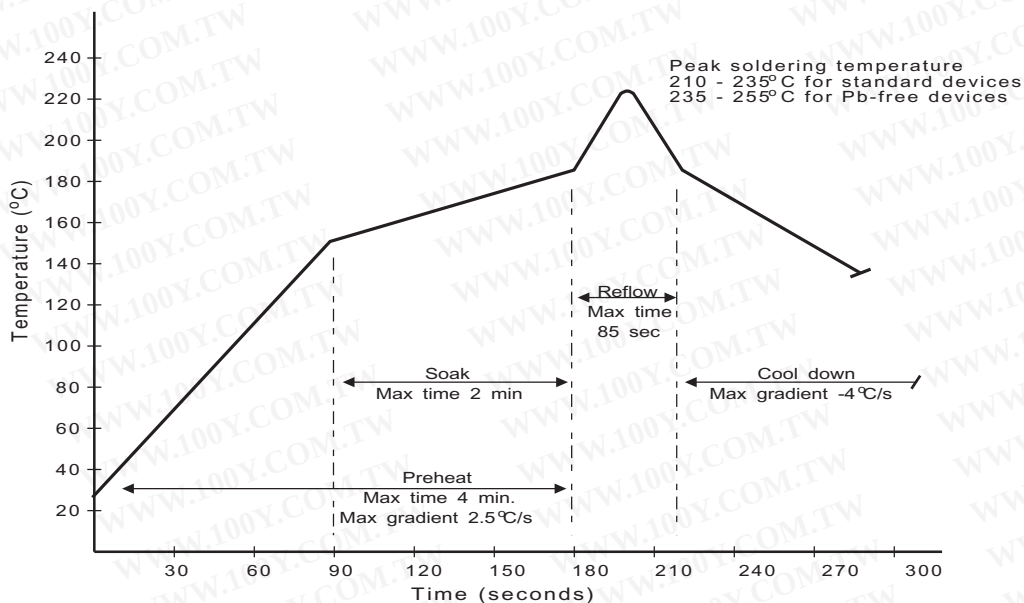


Fig.2 Typical IR Reflow Soldering Thermal Profile